

SILICON POWER TRANSISTOR 2SB601

PNP SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

FEATURES

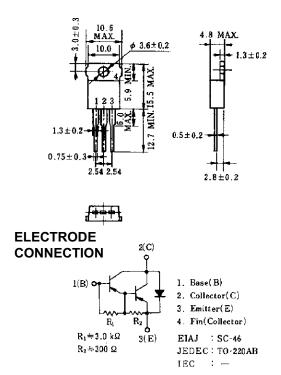
- High-DC current gain due to Darlington connection
- · Low collector saturation voltage
- · Low collector cutoff current
- Ideal for use in direct drive from IC output for magnet drivers such as treminal equipment or cash registers

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{СВО}	-100	V
Collector to emitter voltage	VCEO	-100	V
Emitter to base voltage	V _{EBO}	-7.0	V
Collector current	Ic(DC)	∓5.0	Α
Collector current	IC(pulse)*	∓8.0	Α
Base current	I _{B(DC)}	-0.5	Α
Total power dissipation	P⊤ (Ta = 25°C)	1.5	W
Total power dissipation	P⊤ (Tc = 25°C)	30	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

^{*} PW \leq 10 ms, duty cycle \leq 50%

PACKAGE DRAWING (UNIT: mm)



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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

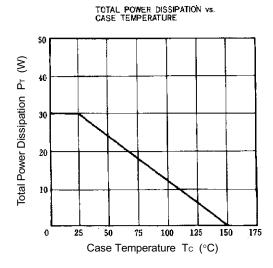
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	$I_C = -3 A$, $I_{B1} = -3 mA$, $L = 1 mH$	-100			V
Collector to emitter voltage	VCEX(SUS)1	$I_{C} = -3 \text{ A}, I_{B1} = -I_{B2} = -3 \text{ mA},$ $V_{BE(OFF)} = 5.0 \text{ V}, L = 180 \ \mu\text{H}, clamped$				V
Collector to emitter voltage	VCEX(SUS)2	Ic = -6 A, I _{B1} = -12 mA, I _{B2} = 3 mA, V _{BE(OFF)} = 5.0 V, L = 180 μ H, clamped	-100			V
Collector cutoff current	Ісво	VcB = -100 V, IE = 0			-10	μΑ
Collector cutoff current	ICER	$V_{CE} = -100 \text{ V}, \text{ R}_{BE} = 51 \Omega, \text{ Ta} = 125^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = -100 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V}$			-10	μΑ
Collector cutoff current	ICEX2	$V_{CE} = -100 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V},$ $Ta = 125^{\circ}C$			-1.0	mA
Emitter cutoff current	Ієво	V _{EB} = -5.0 V, I _C = 0			-3.0	mA
DC current gain	h _{FE1} *	Vce = -2.0 V, Ic = -3.0 A	2,000		15,000	
DC current gain	h _{FE2} *	$V_{CE} = -2.0 \text{ V}, I_{C} = -5.0 \text{ A}$	500			
Collector saturation voltage	V _{CE(sat)} *	$I_C = -3.0 \text{ A}, I_B = -3.0 \text{ mA}$			-1.5	V
Base saturation voltage	V _{BE(sat)} *	$Ic = -3.0 \text{ A}, I_B = -3.0 \text{ mA}$			-2.0	V
Turn-on time	ton	Ic = -3.0 A, R _L = 17 Ω ,		0.5		μs
Storage time	tstg	$I_{B1} = -I_{B2} = -3.0 \text{ mA}, \text{ V}_{CC} \cong -50 \text{ V}$ Refer to the test circuit.		1.0		μs
Fall time	t _f	Tiolor to the test enount.		1.0		μs

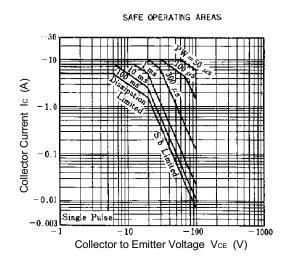
^{*} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

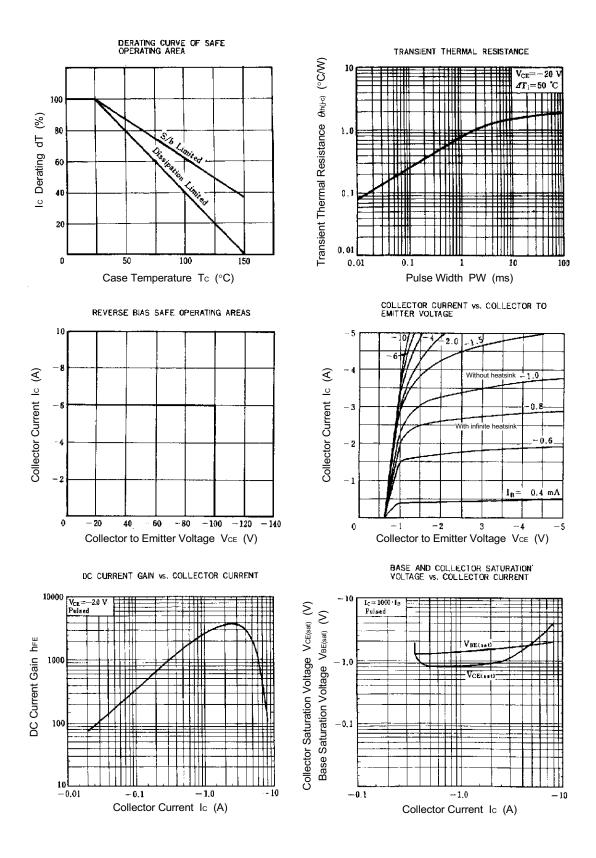
hfe CLASSIFICATION

Marking	М	L	K
h _{FE1}	2,000 to 5,000	3,000 to 7,000	5,000 to 15,000

TYPICAL CHARACTERISTICS (Ta = 25°C)



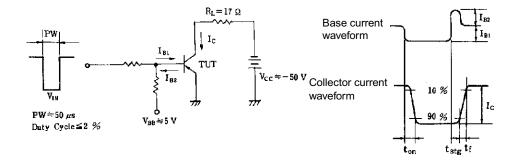




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SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



[MEMO]

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